NSN 5961-01-301-4828

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-301-4828 **Inclosure Material:** Glass **Overall Length:** Between 0.240 inches and 0.255 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.120 inches and 0.127 inches **Function For Which Designed:** Transient suppressor **End Application:** 5940-01-238-4021 terminal, taper pin, electrical **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 11.1 breakdown voltage, dc and 12.3 breakdown voltage, dc **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 1.00 milliamperes drain current pascal **Power Rating Per Characteristic:** 1.0 watts any acceptable preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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